

WIDEBAND MMIC VCO WITH BUFFER AMPLIFIER, 4GHZ TO 8GHZ

Package: QFN, 4mmx4mmx1.1mm



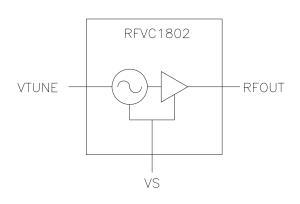


Features

- Wideband Performance
- P_{OUT}=+4.0dBm Typical
- External Resonator Not Required
- Single Bias Supply: +5V at 53mA
- Output Phase Noise: -99dBc/Hz at 100kHz
- Low Profile 4mmx4mm QFN

Applications

- Military Radar, Communications, ECM/IED
- Satcomm Communication Modems
- Test Instrumentation
- Industrial/Medical Equipment



Functional Block Diagram

Product Description

RFMD's RFVC1802 wideband Voltage Controlled Oscillator is a GaAs InGaP HBT MMIC with integrated VCO core and RF output buffer. The part operates from a single +5V supply for circuit bias and 0V to +18V V_{TUNE} for frequency control. The RFVC1802 is a RoHS Compliant, compact QFN, $4\,\text{mmx}4\,\text{mm}$ package that offers low phase noise and low power consumption.

Ordering Information

RFVC1802S2 2 piece sample bag
RFVC1802SB 5 piece bag
RFVC1802SQ 25 piece Sample Bag
RFVC1802SR 100 pieces on 7" reel
RFVC1802TR7 750 pieces on 7" reel
RFVC1802TR13 2500 pieces on 13" reel

RFVC1802PCK-410 Populated Evaluation Board with 2 piece sample bag

Optimum Technology Matching® Applied

□ GaAs HBT	□ SiGe BiCMOS	☐ GaAs pHEMT	☐ GaN HEMT
☐_GaAs MESFET	☐ Si BiCMOS	☐ Si CMOS	☐ BiFET HBT
☑ InGaP HBT	☐ SiGe HBT	☐ Si BJT	LDMOS

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Absolute Maximum Ratings

Parameter	Rating	Unit
Device Operating Voltage (V _S)	5.5	V
V _{TUNE} (V _T)	0 to +20	V
Device Operating Current	80	mA
Operating Temperature Range	-40 to +85	°C
Storage Temperature Range	-65 to +150	°C
Operating Junction Temperature (T _J)	+140	°C
ESD Rating - Human Body Model (HBM)	Class 0	



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

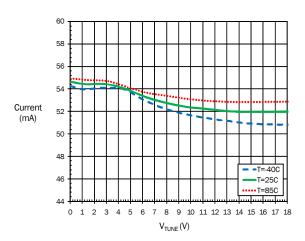
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Parameter	Specification		Unit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition
Overall					V _S =5V, Freq=4GHz to 8GHz, T=25 °C unless noted otherwise.
Frequency of Operation	4.0		8.0	GHz	
Supply Voltage (V _S)	4.75	5.00	5.25	V	Recommended operating range
Supply Current	40	53	70	mA	
Tuning Voltage (V _{TUNE})	0		18	V	
Tuning Sensitivity		270		MHz/V	
Output Power		4.0		dBm	
Output Phase Noise at 10kHz		-74		dBc/Hz	
Output Phase Noise at 100kHz		-99		dBc/Hz	
2nd Harmonic		-20		dBc	
Frequency Pushing		15		MHz/V	
Frequency Pulling (2:1 VSWR)		3		MHz pp	
RF Output Return Loss		10		dB	
Frequecy Drift Rate		-0.6		MHz/°C	
V _{TUNE} Port Input Capacitance		4		pF	
Thermal Resistance		45		°C/W	Junction to paddle



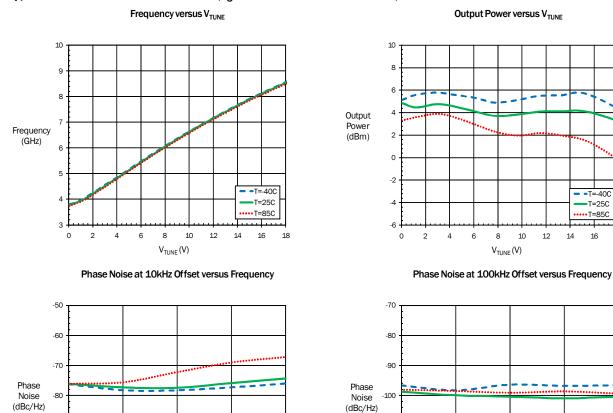
Typical Evaluation Board Performance (V_S=5.0V unless otherwise noted)

Supply Current versus V_{TUNE}





Typical Evaluation Board Performance (V_S=5.0V unless otherwise noted)



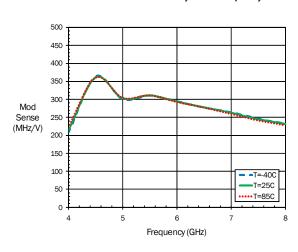
- T=-40C

****T=85C

-T=25C



Frequency (GHz)



5

Frequency (GHz) Pushing versus Frequency

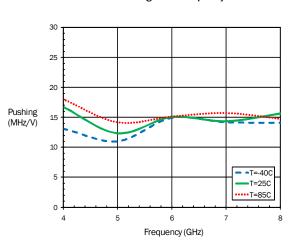
12

16

-T=-40C

----T=85C

-T=25C



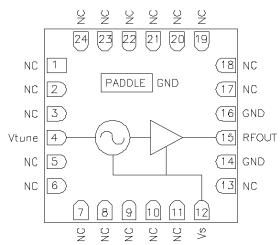
-120

-100



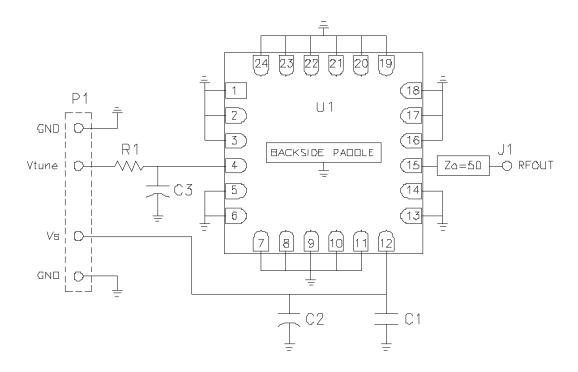
Pin	Function	Description
1-3,	NC	No internal connection. Connect to PCB ground.
5-11,		
1 3,		
17-24		
4	VTUNE	VCO control voltage input
12	VS	Supply voltage input for the VCO and Buffer stage.
14,16	GND	Pin internally bonded to package paddle. Connect to PCB ground.
15	RFOUT	VCO RF output. Pin is internally DC-blocked.
Pad- dle	GND	Exposed paddle on backside needs to be soldered to PCB ground.

Pin Out





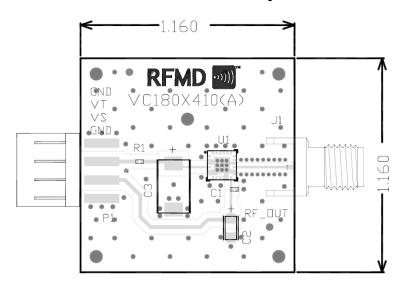
Evaluation Board Schematic



Item	Description	
U1	RFVC1802	
C1	CAP, 1000pF, 0402	
C2	CAP, 4.7 uF, TANT-A	
C3	CAP, 22 uF, TANT-D	
R1	Jumper, 0Ω, 0402	
P1	CONN, HDR, ST, PLRZD, 4-Pin, 0.100"	
J1	CONN, SMA, END Launch	

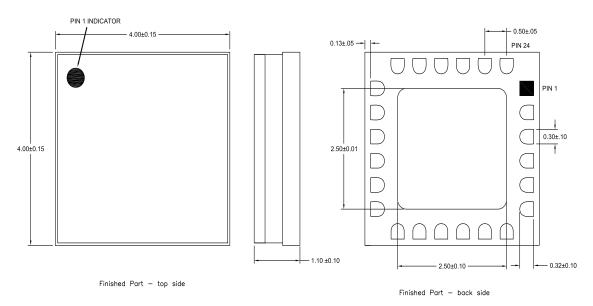


Evaluation Board Layout





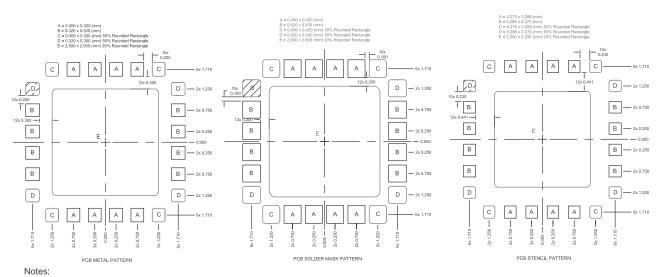
Package Drawing



Notes:

- 1. Dimensions in mm.
- 2. Dimensions are for reference only.
- 3. Package body material: Alumina.
- 4. Lead and paddle plating: Au, 30 u" minimum.

Recommended PCB Layout



1. Shaded area represents Pin 1 location.